# imall

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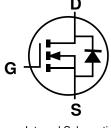
## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
	$38m\Omega @ V_{GS} = 4.5V$	4.0A
20V	45mΩ @ V <sub>GS</sub> = 2.5V	3.7A

## **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Battery Charging
- **Power Management Functions**
- **DC-DC Converters**
- Portable Power Adaptors



Internal Schematic

## 20V N-CHANNEL ENHANCEMENT MODE MOSFET

## **Features and Benefits**

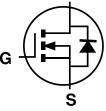
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

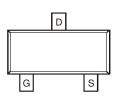
### Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



**Top View** 





Top View

## Ordering Information (Note 4)

	Part Number	Case	Packaging		
	DMN2056U-7	SOT23	3000/Tape & Reel		
DMN2056U-13		SOT23	10000/Tape & Reel		
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.					

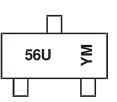
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



56U = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: D = 2016) M = Month (ex: 9 = September)

#### Date Code Key

Duie Coue Rey												
Year	2016		2017	2018		2019	2020		2021	2022		2023
Code	D		E	F		G	Н		I	J		K
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



## **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V <sub>DSS</sub>	20	V
Gate-Source Voltage	V <sub>GSS</sub>	±8	V
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	ID	4.0 3.2	А
Maximum Body Diode Forward Current (Note 6)	Is	1.0	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	22	А

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		PD	0.66	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>θJA</sub>	192	°C/W
Power Dissipation (Note 6)		PD	0.94	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>θJA</sub>	136	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	20	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.4	0.6	1.0	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
		_	30	38		$V_{GS} = 4.5V, I_D = 3.6A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	34	45	mΩ	$V_{GS} = 2.5V, I_D = 3.1A$
	. ,	_	52	85		V <sub>GS</sub> = 1.5V, I <sub>D</sub> = 2.0A
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		339	—		V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V f = 1.0MHz
Output Capacitance	C <sub>oss</sub>	_	47	—	pF	
Reverse Transfer Capacitance	Crss	_	34	—		
Gate Resistance	R <sub>G</sub>	_	2.6	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge	Qg	_	4.3	_		
Gate-Source Charge	Q <sub>gs</sub>	_	0.5	_	nC	$V_{DS} = 10V, V_{GS} = 4.5V, I_D = 3.6A$
Gate-Drain Charge	Q <sub>gd</sub>	_	0.8	_		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	1.8	_		
Turn-On Rise Time	t <sub>R</sub>		2.8	_		$V_{GS} = 4.5V, V_{DD} = 10V, R_{G} = 1\Omega,$
Turn-Off Delay Time	tD(OFF)	_	8.5	_	ns	I <sub>D</sub> = 3.6A
Turn-Off Fall Time	tF		1.7			
Body Diode Reverse Recovery Time	t <sub>RR</sub>		4.7		ns	I <sub>F</sub> = 3.6A, dI/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>		0.7		nC	I <sub>F</sub> = 3.6A, dI/dt = 100A/µs

Notes:

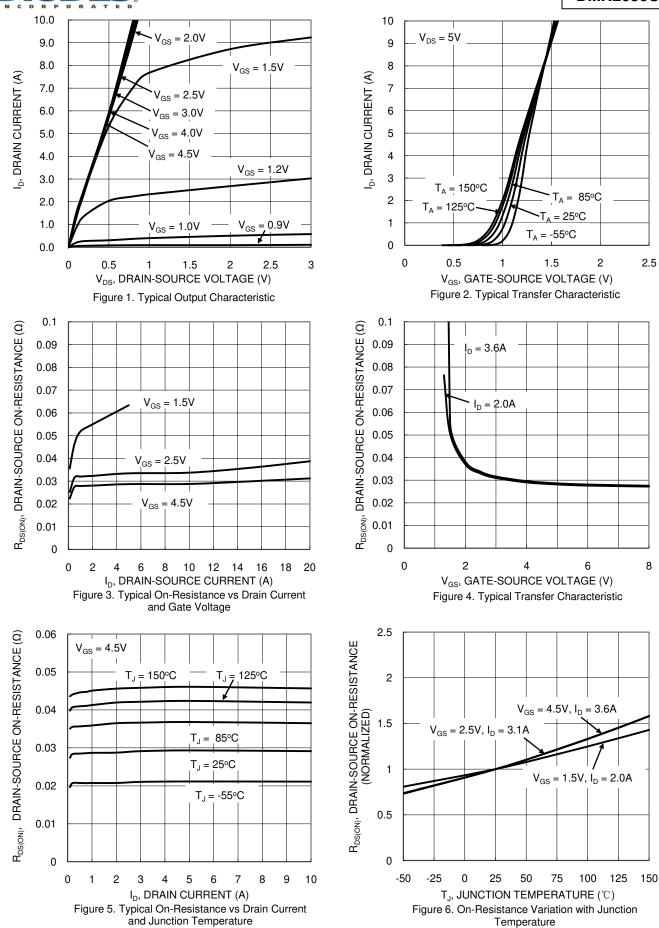
Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.



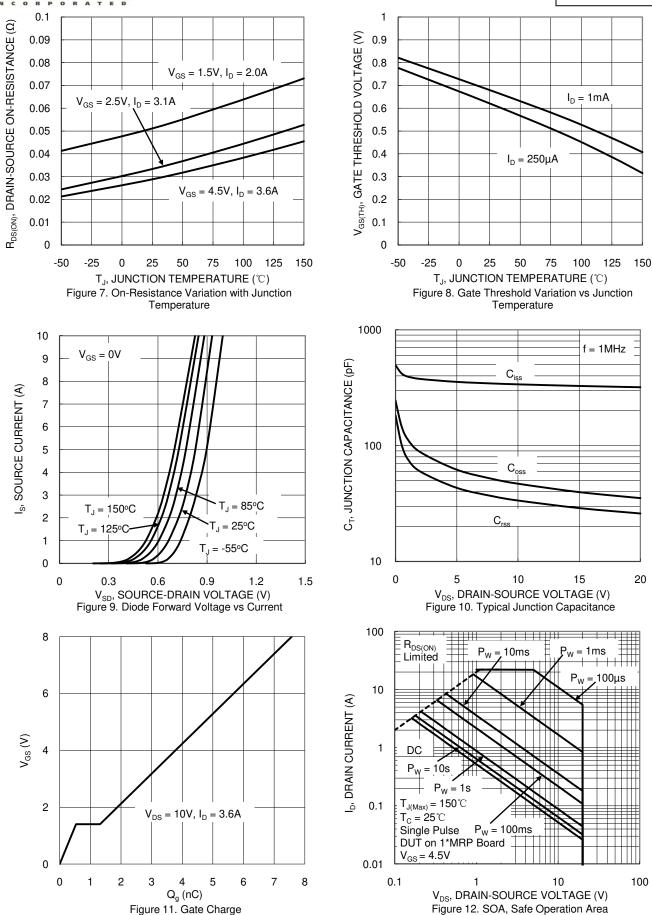




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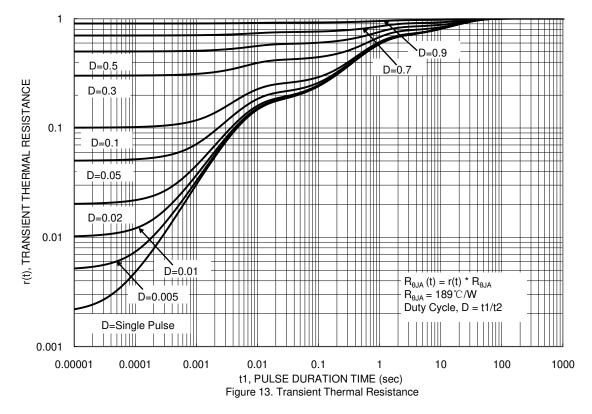


## DMN2056U



DMN2056U Document number: DS38480 Rev. 1 - 2



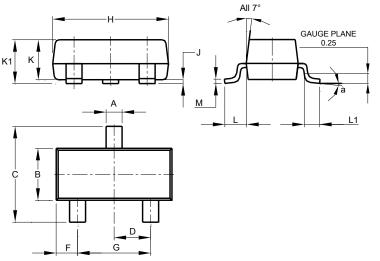




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
К	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Y1 С ⊢Х-X1

SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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